

Electronics

# 2 Watt C-Band VSAT Power Amplifier 5.9 - 7.1 GHz

#### Features

- High Linear Gain: 33 dB Typical
- High Saturated Output Power: +33 dBm Typ.
- High Power Added Efficiency: 25% Typ.
- 50 Ω Input / Output Broadband Matched
- Integrated Output Power Detector
- Lead-Free Bolt Down Ceramic Package
- RoHS\* Compliant and 260°C Reflow Compatible

#### Description

M/A-COM's AM42-0039 is a three stage MMIC power amplifier in a lead-free, bolt down ceramic package, allowing easy assembly. The AM42-0039 employs a fully matched chip with internally decoupled gate and drain bias networks. The AM42-0039 is designed to operate from a constant current drain supply or a constant voltage gate supply. By varying the bias conditions, the saturated output power performance of this device may be tailored for various applications.

The AM42-0039 is ideally suited for use as an output stage or a driver amplifier in VSAT systems. The AM42-0039 includes internal supply line bypassing in the package, minimizing the number of external components required.

M/A-COM's AM42-0039 is fabricated using a mature 0.5 micron MBE based GaAs MESFET process. The process features full passivation for increased performance and reliability. This product is 100% RF tested to ensure compliance to performance specifications.

#### **Ordering Information**

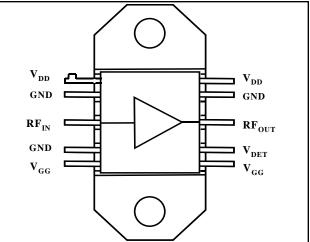
Part Number	Package	
AM42-0039	CR-15 Ceramic Bolt Down Package	





AM42-0039 V3

#### **Functional Schematic**



#### **Pin Configuration**

Pin No.	Pin Name	Description	
1	V <sub>DD</sub>	Drain Supply	
2	GND	DC and RF Ground	
3	RF <sub>IN</sub>	RF Input	
4	GND	DC and RF Ground	
5	V <sub>GG</sub>	Gate Supply	
6	V <sub>GG</sub>	Gate Supply	
7	V <sub>DET</sub>	Output Power Detector	
8	RF <sub>OUT</sub>	RF Output	
9	GND	DC and RF Ground	
10	V <sub>DD</sub>	Drain Supply	
Flange	GND	DC and RF Ground	

\* Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

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# RoHS Compliant



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AM42-0039 V3

## Electrical Specifications: $T_A = +25$ °C, $V_{DD} = +8$ V, $V_{GG}$ adjusted for $I_{DD} = 900$ mA, F = 5.9 - 7.1 GHz

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Parameter	Test Conditions	Units	Min.	Тур.	Max.
Linear Gain	P <sub>IN</sub> = -10 dBm	dB	31	33	35
Input VSWR	P <sub>IN</sub> = -10 dBm	Ratio		2.5:1	3.0:1
Output VSWR	P <sub>IN</sub> = -10 dBm	Ratio	_	2.5:1	_
Output Power	P <sub>IN</sub> = +3 dBm, lds = 900 mA Typ.	dBm	31.7	33.0	—
Output Power vs. Frequency	$P_{IN}$ = +3 dBm, Ids = 900 mA Typ. (5.9 to 6.4 GHz) $P_{IN}$ = +3 dBm, Ids = 900 mA Typ. (6.4 to 7.1 GHz)	dB dB		±0.3 ±0.3	±0.75 ±0.75
Output Power vs. Temperature	$T_A = -40^{\circ}C$ to $+85^{\circ}C$ , $P_{IN} = +7$ dBm	dB	—	±0.4	—
Drain Bias Current	P <sub>IN</sub> = +3 dBm	mA	800	900	1000
Gate Bias Voltage	$P_{IN}$ = +3 dBm, Ids = 900 mA Typ.	V	-2.0	-1.2	-0.4
Gate Bias Current	P <sub>IN</sub> = +3 dBm, lds = 900 mA Typ.	mA	_	10	20
Thermal Resistance (qJC)	25°C Heat Sink	°C/W	_	7.0	_
Second Harmonic	P <sub>IN</sub> = +3 dBm, lds = 900 mA Typ.	dBc	_	-35	—
Third Harmonic	P <sub>IN</sub> = +3 dBm, lds = 900 mA Typ.	dBc	_	-45	—
Detector Voltage	P <sub>IN</sub> = +3 dBm, lds = 900 mA Typ.	V	_	4.0	—

# Absolute Maximum Ratings<sup>1,2,3</sup>

Parameter	Absolute Maximum		
Input Power	+15 dBm		
Operating Voltages	$V_{DD}$ = +10 volts; $V_{GG}$ = -3 volts; $V_{DD}$ - $V_{GG}$ = 12 volts		
lds	1200 mA		
Channel Temperature	+150 °C		
Operating Temperature	-40 °C to +80 °C		
Storage Temperature	-65 °C to +150 °C		

1. Exceeding any one or combination of these limits may cause permanent damage to this device.

- 2. M/A-COM does not recommend sustained operation near these survivability limits.
- 3. Adequate heat sinking and grounding required on flange base.

#### **Operating the AM42-0039**

The AM42-0039 is static sensitive. Please handle with care. To operate the device, follow these steps.

- 1. Apply -2.0 Volts to  $V_{GG}$ .
- 2. Ramp  $V_{DD}$  to +8V.
- 3. Adjust  $V_{\text{GG}}$  to set  $\,$  quiescent drain current .
- 4. Apply RF.
- 5. Power down in reverse sequence. Turn gate voltage off last.

#### Handling Procedures

Please observe the following precautions to avoid damage:

#### **Static Sensitivity**

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

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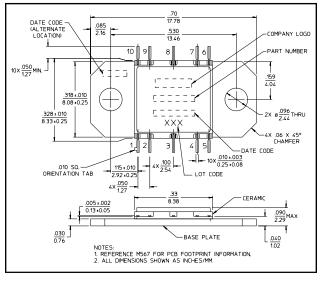
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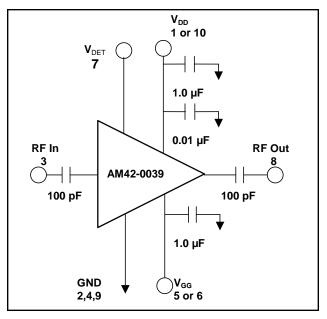
AM42-0039 V3

## Lead-Free CR-15<sup>†</sup>



<sup>†</sup> Reference Application Note M538 for lead-free solder reflow recommendations.

#### Application Schematic <sup>4,5,6</sup>



- Apply -2 volts to pin 5 or 6 (V<sub>GG</sub>), prior to applying +8 volts to pins 1 or 10 (V<sub>DD</sub>). Adjust V<sub>GG</sub> for typical drain current.
- 5. External DC blocking capacitors required on the RF ports.
- For optimum IP3 performance, V<sub>DD</sub> bypass capacitors should be placed within 0.5 inches of the V<sub>DD</sub> leads.

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